

General Description

The MAX3370/MAX3371 logic level translators are ideal for applications interfacing low-voltage devices to other logic levels. Externally applied voltages set the logic levels of the MAX3370/MAX3371. The devices accept V_{CC} from +2.5V to +5.5V and V_L from +1.6V to +5.5V, allowing data transfer between low-voltage ASICs and higher voltage devices. The MAX3371 features a shutdown mode that reduces supply current to <1µA and puts the I/O pins in a high-impedance state.

The MAX3370/MAX3371 are bidirectional level shifters, allowing data transfer from the V_{CC} side to the V_L side and from the V_L side to the V_{CC} side. Both devices operate at speeds up to 2Mbps with an active driver and up to 500kbps with an open-drain driver.

The MAX3370/MAX3371 are available in space-saving 5-pin and 6-pin SC70 packages, respectively.

Applications

Cell Phone Cradles

Cell Phone Hands-Free Kits

Portable POS Systems

Portable Communication Devices

Smart Card Readers

SPI™, MICROWIRE™, and I²C™ Level Translation

Low-Voltage ASIC Level Translation

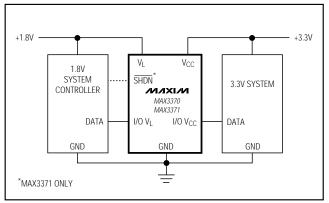
RS-232-Compatible Translation

I²C is a trademark of Philips Corp.

SPI is a trademark of Motorola, Inc.

MICROWIRE is a trademark of National Semiconductor Corp.

Typical Operating Circuit



†MAX3370/MAX3371 covered by U.S. Patent number 5,894,240.

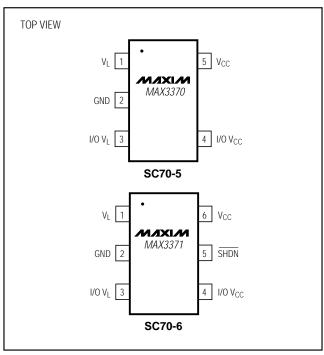
Features

- ♦ Allow Bidirectional Level Translation
- ♦ Miniature SC70 Packages
- ♦ Operational Down to 1.6V
- ♦ Low Quiescent Current (<100µA)</p>
- ♦ Ultra-Low (<1µA) Shutdown Supply Current (MAX3371)
- ♦ Three-State Outputs in Shutdown (MAX3371)
- ◆ 2Mbps (10pF Load) Push-Pull Driving
- ◆ 1Mbps (50pF Load) Push-Pull Driving
- ♦ 500kbps (30pF Load) Open-Drain Driving

Ordering Information

PART	TEMP. PIN- RANGE PACKAGE		SHDN	TOP MARK	
MAX3370EXK-T	-40°C to +85°C	5 SC70-5	NO	ABV	
MAX3371EXT-T	-40°C to +85°C	6 SC70-6	YES	AAO	

Pin Configurations



/U/IXI/U

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ABSOLUTE MAXIMUM RATINGS

V _{CC} to GND0.3V to +7V	Continuous Power Dissipation ($T_A = +70^{\circ}C$)
SHDN to GND0.3V to (V _L + 0.3V)	5/6-Pin SC70 (derate 3.1mW/°C above +70°C)245mW
I/O V _L to GND0.3V to (V _L + 0.3V)	Operating Temperature Range40°C to +85°C
V _L , I/O V _{CC} to GND0.3V to (V _{CC} + 0.3V)	Storage Temperature Range65°C to +150°C
Short-Circuit Duration: I/O V _L , I/O V _{CC} to GNDContinuous	Lead Temperature (soldering, 10s)+300°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

 $(V_{CC} = +2.5V \text{ to } +5.5V, V_L = +1.6V \text{ to } +5.5V \text{ (Note 1), GND} = 0$; I/O V_L , I/O V_{CC} unconnected; $T_A = -40^{\circ}C$ to $+85^{\circ}C$, unless otherwise noted. Typical values are at $T_A = +25^{\circ}C$.) (Note 2)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
POWER SUPPLIES	•		•			•
V _L Supply Range	VL	(Note 1)	1.6		5.5	V
V _{CC} Supply Range	Vcc		2.5		5.5	V
Supply Current from V _{CC}	lavcc			70	100	μΑ
Supply Current from V _L	IQVL			5	100	μΑ
V _{CC} Shutdown Supply Current		$\overline{SHDN} = GND, T_A = +25^{\circ}C, MAX3371$		0.03	1	μΑ
V _L Shutdown Supply Current		$\overline{SHDN} = GND, T_A = +25^{\circ}C, MAX3371$		0.03	1	μΑ
Three-State Output Leakage Current		I/O V_L , I/O V_{CC} ; $\overline{SHDN} = GND$, $T_A = +25$ °C, MAX3371		0.02	1	μΑ
LOGIC LEVEL THRESHOLDS						
I/O V _L Input Voltage High Threshold	VIHL				V _L - 0.2	V
I/O V _L Input Voltage Low Threshold	VILL		0.15			V
I/O V _{CC} Input Voltage High Threshold	V _{IHC}				V _{CC} - 0.4	V
I/O V _{CC} Input Voltage Low Threshold	VILC		0.2			V
I/O V _L Output Voltage High	Vohl	I/O V _L sink current = 20μ A, I/O V _{CC} \geq V _{CC} - 0.4V (Note 3)	2/3 × V _L			V
I/O V _L Output Voltage Low	Voll	I/O V_L sink current = 1mA, I/O $V_{CC} \le 0.2V$ (Note 3)			0.4	V
I/O V _{CC} Output Voltage High	V _{OHC}	I/O V _{CC} source current = 20μ A, I/O V _L \geq V _L - 0.2V (Note 3)	2/3 × V _{CC}			V
I/O V _{CC} Output Voltage Low	Volc	I/O V _{CC} sink current = 1mA, I/O V _L ≤ 0.15V (Note 3)			0.4	V
SHDN Input Voltage High	VIH-SHDN		2/3 × V _L			V
CLIDAL Inc. of Maltanes I am	.,	V _L ≥ +1.8V			0.4	
SHDN Input Voltage Low	VIL-SHDN	V _L ≥ +1.6V			0.2	V

ELECTRICAL CHARACTERISTICS (continued)

(V_{CC} = +2.5V to +5.5V, V_L = +1.6V to +5.5V (Note 1), GND = 0; I/O V_L , I/O V_{CC} unconnected; T_A = -40°C to +85°C, unless otherwise noted. Typical values are at T_A = +25°C.) (Note 2)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	
TIMING CHARACTERISTICS ($R_{LOAD} = 1M\Omega$, $V_{CC} = +2.5V$, $V_L = +1.6V$, V_C test signal Rail-to-Rail® unless otherwise noted, Figure 1) (Note 3)							
I/O V _{CC} Rise Time (Note 4)		C _{LOAD} = 10pF, data rate = 2Mbps (Note 5)			100		
	tp://00	C _{LOAD} = 50pF, data rate = 1Mbps			200	nc	
	tRVCC	C _{LOAD} = 30pF, data rate = 500kbps, open-drain drive			400	ns	
		C _{LOAD} = 10pF, data rate = 2Mbps (Note 5)			50	ns	
I/O V _{CC} Fall Time	tFVCC	C _{LOAD} = 50pF, data rate = 1Mbps			200		
(Note 4)	15000	C _{LOAD} = 30pF, data rate = 500kbps, open-drain drive			400	113	
		C _{LOAD} = 10pF, data rate = 2Mbps (Note 5)			100		
I/O V _L Rise Time	t _{RVL}	C _{LOAD} = 50pF, data rate = 1Mbps			200]	
(Note 4)	I KVL	C _{LOAD} = 30pF, data rate = 500kbps, open-drain drive			400	ns	
		C _{LOAD} = 10pF, data rate = 2Mbps (Note 5)			50		
I/O V _L Fall Time	tr. u	C _{LOAD} = 50pF, data rate = 1Mbps			200	nc	
(Note 4)	tFVL	C _{LOAD} = 30pF, data rate = 500kbps, open-drain drive			400	ns	
		C _{LOAD} = 10pF, data rate = 2Mbps (Note 5)			50		
HIGH-to-LOW Transition Propagation Delay	tpD-VCC-HL	C _{LOAD} = 50pF, data rate = 1Mbps			200	ns	
(Driving I/O V _L)	PD-VCC-FIL	C _{LOAD} = 30pF, data rate = 500kbps, open-drain drive			400		
1000		C _{LOAD} = 10pF, data rate = 2Mbps (Note 5)			200		
LOW-to-HIGH Transition Propagation Delay	top vec III	C _{LOAD} = 50pF, data rate = 1Mbps			400	ns	
(Driving I/O V _L)	tPD-VCC-LH	C _{LOAD} = 30pF, data rate = 500kbps, open-drain drive			800		
		C _{LOAD} = 10pF, data rate = 2Mbps (Note 5)			50		
HIGH-to-LOW Transition Propagation Delay (Driving I/O V _{CC})	tpD-VL-HL	C _{LOAD} = 50pF, data rate = 1Mbps			200	ns	
	PD-VL-HL	C _{LOAD} = 30pF, data rate = 500kbps, open-drain drive			400		
LOW-to-HIGH Transition Propagation Delay (Driving I/O V _{CC})		C _{LOAD} = 10pF, data rate = 2Mbps (Note 5)			200		
	top vii i i i	C _{LOAD} = 50pF, data rate = 1Mbps			400	ns ns	
	tPD-VL-LH	C _{LOAD} = 30pF, data rate = 500kbps, open-drain drive			800		
HIGH-to-LOW Transition		C _{LOAD} = 10pF, data rate = 2Mbps (Note 3)		2			
Propagation Delay		C _{LOAD} = 50pF, data rate = 1Mbps		4		ns	
Device-to-Device Skew (Driving I/O V _L)		C _{LOAD} = 30pF, data rate = 500kbps, open-drain drive		5			

Rail-to-Rail is a registered trademark of Nippon Motorola Ltd.



ELECTRICAL CHARACTERISTICS (continued)

 $(V_{CC} = +2.5V \ to \ +5.5V, \ V_L = +1.6V \ to \ +5.5V \ (Note \ 1), \ GND = 0; \ I/O \ V_L, \ I/O \ V_{CC} \ unconnected; \ T_A = -40^{\circ}C \ to \ +85^{\circ}C, \ unless \ otherwise noted. \ Typical values are at \ T_A = +25^{\circ}C.) \ (Note \ 2)$

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
LOW-to-HIGH Transition		C _{LOAD} = 10pF, data rate = 2Mbps (Note 3)		5		ns
Propagation Delay		C _{LOAD} = 50pF, data rate = 1Mbps		8		
Device-to-Device Skew (Driving I/O V _L)		C _{LOAD} = 30pF, data rate = 500kbps, open-drain drive		80		
HIGH-to-LOW Transition Propagation Delay Device-to-Device Skew (Driving I/O V _{CC})		C _{LOAD} = 10pF, data rate = 2Mbps (Note 3)		2		ns
	Delay	C _{LOAD} = 50pF, data rate = 1Mbps		4		
		C _{LOAD} = 30pF, data rate = 500kbps, open-drain drive		5		
		C _{LOAD} = 10pF, data rate = 2Mbps (Note 3)		7		ns
Propagation Delay		C _{LOAD} = 50pF, data rate = 1Mbps		8		
Device-to-Device Skew (Driving I/O V _{CC})		C _{LOAD} = 30pF, data rate = 500kbps, open-drain drive		50		
Maximum Data Rate		C _{LOAD} = 10pF (Note 5)	2	3		
		C _{LOAD} = 50pF	1	2		Mbps
		C _{LOAD} = 30pF, open-drain drive	0.5	1		

Note 1: V_L must always be less than or equal to V_{CC}.

Note 2: All units are 100% production tested at T_A = +25°C. Limits over the operating temperature range are guaranteed by design and not production tested.

Note 3: Tested only at worst case: $V_{CC} = +2.5V$, $V_L = +1.6V$.

Note 4: 10% to 90%.

Note 5: Guaranteed by correlation to $C_{LOAD} = 50pF$.

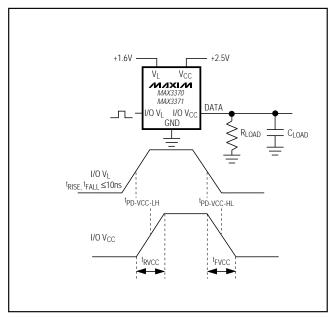


Figure 1a. Rail-to-Rail Driving I/O VL

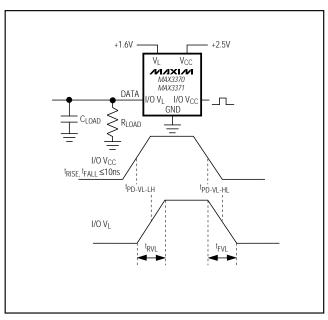


Figure 1b. Rail-to-Rail Driving I/O VCC

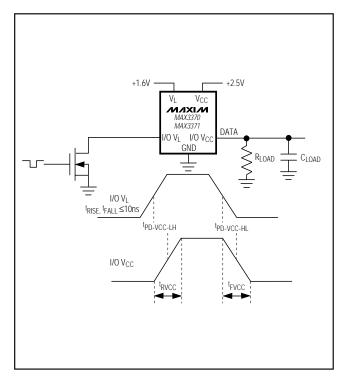


Figure 1c. Open-Drain Driving I/O VL

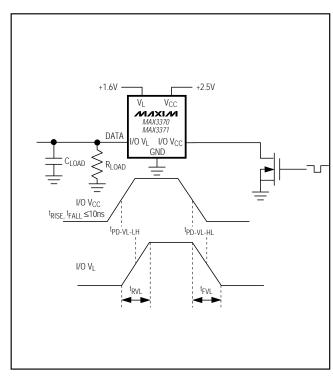


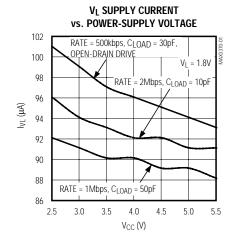
Figure 1d. Open-Drain Driving I/O V_{CC}

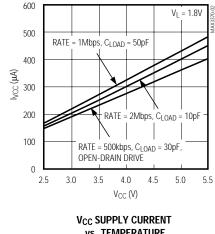
Typical Operating Characteristics

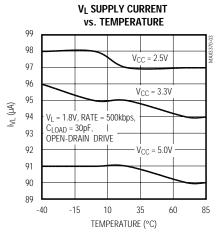
V_{CC} SUPPLY CURRENT

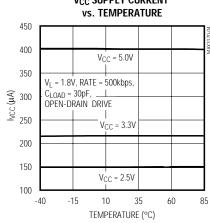
vs. POWER-SUPPLY VOLTAGE

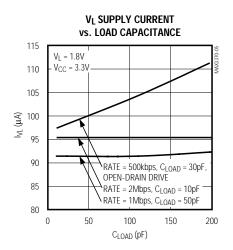
(Driving I/O V_L rail-to-rail, R_L = $1M\Omega$, T_A = +25°C, unless otherwise noted.)

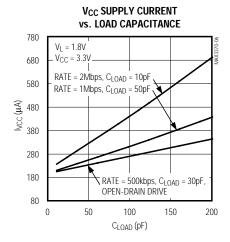






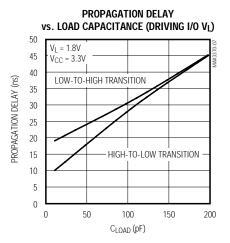


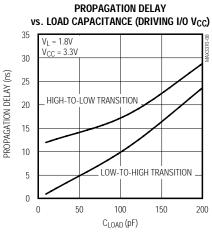


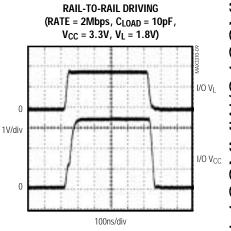


Typical Operating Characteristics (continued)

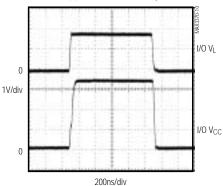
(Driving I/O VL rail-to-rail, RL = 1M Ω , TA = +25°C, unless otherwise noted.)

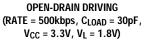


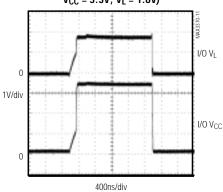




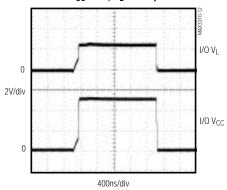
 $\begin{array}{l} \text{RAIL-TO-RAIL DRIVING} \\ \text{(RATE = 1Mbps, $C_{LOAD} = 50pF,} \\ \text{$V_{CC} = 3.3V, $V_{L} = 1.8V$)} \end{array}$



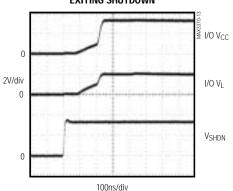




OPEN-DRAIN DRIVING (RATE = 500kbps, C_{LOAD} = 30pF, V_{CC} = 5V, V_L = 2.5V)







Pin Description

F	PIN	NAME	FUNCTION
MAX3370	MAX3371	NAME	FUNCTION
1	1	VL	Logic Supply Voltage
2	2	GND	Ground
3	3	I/O VL	Input/Output Referred to V _L
4	4	I/O V _{CC}	Input/Output Referred to V _{CC}
5	6	Vcc	Power-Supply Voltage
_	5	SHDN	Shutdown. A high turns on the device. A low shuts down the device. I/O V_{CC} and I/O V_{L} are high impedance in shutdown.

Detailed Description

The MAX3370/MAX3371 provide the necessary level translation to allow data transfer in a multivoltage system. These devices transmit data between an I/O pin referenced to V_{CC} and an I/O pin referenced to V_{L} . The V_{CC} supply voltage range is from +2.5V to +5.5V, and the V_{L} supply voltage range is between +1.6V and +5.5V. The MAX3371 features a shutdown mode in which I/O V_{CC} and I/O V_{L} are placed in a high-impedance state and supply current drops to 1 μA .

The MAX3370/MAX3371 are bidirectional level shifters allowing data transfer from the V_{CC} side to the V_L side, and from the V_L side to the V_{CC} side. Both devices operate at speeds up to 2Mbps with an active driver and up to 500kbps with an open-drain driver.

Level Translation

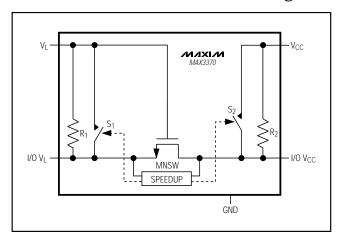
The MAX3370/MAX3371 provide bidirectional level translation between I/O pins referred to V_{CC} and V_L. I/O V_{CC} and I/O V_L are internally pulled up to their respective power-supply rails through 10k Ω resistors. V_{CC} must be between +2.5V and +5.5V, and V_L must be between +1.6V and +5.5V. For proper operation, V_L can not exceed V_{CC}.

The MAX3370/MAX3371 can operate at data rates up to 2Mbps when driven by an active (push-pull) driver with a 10pF load, 1Mbps when driven by an active driver with a 50pF load, or 500kbps when driven by an open-drain driver with a 30pF load. The internal pullups allow these devices to be driven by open-drain drivers.

MAX3371 Shutdown Mode

The MAX3371 enters a low-power shutdown mode when \overline{SHDN} is driven low. Connect \overline{SHDN} to V_L or drive high for normal operation. Activating shutdown mode disconnects the internal 10k Ω pullup resistors on I/O

Functional Diagram



 V_{CC} and I/O V_L . As a result, the supply current decreases to <1 μ A, and the I/O lines are high impedance. The high impedance I/O lines in shutdown allow use in a multidrop network. When in shutdown, I/O V_L can be driven to V_L and I/O V_{CC} can be driven to V_{CC} .

Speed-Up

The speed-up circuit is a one-shot generator that helps the rise time of the output waveform in the low-to-high transition. When triggered, switches S_1 and S_2 turn on for 320ns to pull up I/O V_L and I/O V_{CC} . This greatly reduces the rise time and propagation delay for the low-to-high transition as well as improves the duty cycle (closer to 50% for an ideal square-wave input). See the scope plots in the *Typical Operating Characteristics* for the speed-up circuitry in operation.

_Applications Information

Power-Supply Decoupling

To reduce ripple and the chance of transmitting incorrect data, decouple V_{CC} and V_L to ground with a $0.1\mu F$ capacitor as close to the device as possible.

I²C Level Translation

The MAX3370/MAX3371 are ideal for level translation between a low-voltage ASIC and an I²C device. The devices' bidirectional natures allow their use in the data line of I²C communications. A typical application is interfacing a low-voltage microprocessor to a 3V or 5V D/A converter, such as the MAX517.

The I/O lines on the MAX3370/MAX3371 are bidirectional, can be level-shifted up to +5.5V, and contain internal $10k\Omega$ pullup resistors to allow open-drain driving (see the *Typical Operating Circuit*).

Push-Pull vs. Open-Drain Driving

The MAX3370/MAX3371 I/O pins can be driven by a push-pull or open-drain device. When using a push-pull driver, the MAX3370/MAX3371 operate up to 2Mbps with a 10pF load or 1Mbps with a 50pF load. The internal pullup resistors on the I/O pins allow use with opendrain devices. The MAX3370/MAX3371 operate up to 500kbps with a 30pF load when driven by an opendrain device.

Data rates higher than those listed in the *Electrical Characteristics* table can be achieved. The maximum data rate is limited to 3Mbps by the speed-up circuitry.

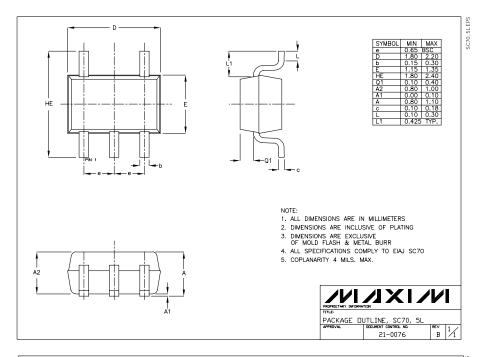
Unidirectional vs. Bidirectional Level Translator

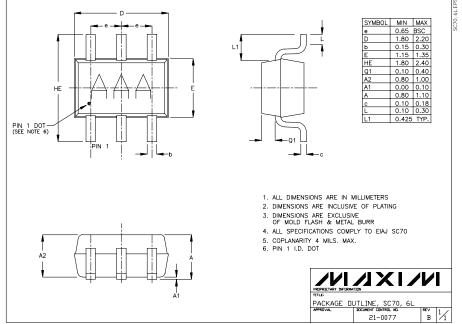
The MAX3370/MAX3371 may also be used to translate unidirectional signals without signal inversion. The devices provide the smallest solution (SC70 package) for unidirectional level translation without inversion.

_____Chip Information

TRANSISTOR COUNT: 75
PROCESS: BICMOS

Package Information





Maxim cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Maxim product. No circuit patent licenses are implied. Maxim reserves the right to change the circuitry and specifications without notice at any time.

10 _____Maxim Integrated Products, 120 San Gabriel Drive, Sunnyvale, CA 94086 408-737-7600